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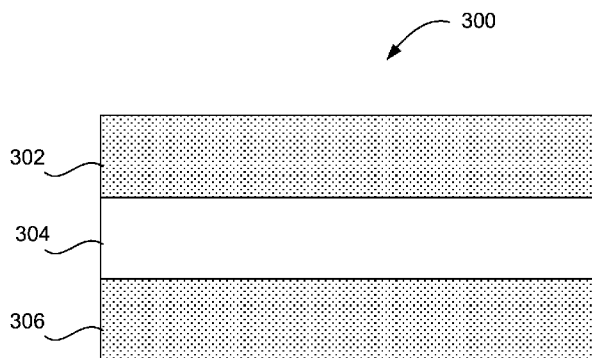


Figure 3

(57) Abstract: A multilayer stack is described. The multilayer stack includes: (i) one or more inorganic barrier layers for reducing transport of gas or vapor molecules therethrough; (ii) an inorganic reactive layer disposed adjacent to one or more of the inorganic barrier layers, and the reactive layer capable of reacting with the gas or the vapor molecules; and (iii) wherein, in an operational state of the multilayer stack, the vapor or the gas molecules that diffuse through one or more of the inorganic barrier layers react with the inorganic reactive layer, and thereby allow said multilayer stack to be substantially impervious to the gas or the vapor molecules.



**AN INORGANIC MULTILAYER STACK AND METHODS AND COMPOSITIONS RELATING
THERE TO**

RELATED APPLICATION

5 The application claims priority from U.S. Provisional Application having Serial Nos.,
61/436,726, 61/436,732 and 61/436,744, each of which was filed on January 27, 2011, and each
of which is incorporated herein by reference for all purposes.

FIELD OF THE INVENTION

10 The present invention relates generally to multilayer stacks and methods and
compositions thereof. More particularly, the present invention relates to flexible multilayer
stacks used as encapsulants in such applications as solar cells, electrolytic cells, solid state
lighting and light-emitting diode (“LED”) display fabrication.

BACKGROUND OF THE INVENTION

15 Many products, such as electronic devices, medical devices and pharmaceuticals, are
sensitive to water vapor and ambient gases, and exposure to them causes product deterioration
and/or product performance degradation. Consequently, blocking coatings are commonly used as
a protective measure to safeguard against such undesired exposure.

20 Plastic coating or layers are frequently used as blocking coatings. Unfortunately, they
suffer from poor gas and liquid permeation resistance, which have values that are typically
several orders of magnitude below the requisite value of permeation resistance for acceptable
product performance. By way of example, certain LED display and solar cell encapsulation
applications require water vapor transmission on the order of $<10^{-4}$ grams/square meter/day, and
in contrast, the water vapor transmission rate for Polyethylene Terephthalate (PET), a commonly
used plastic substrate, is in the order of between about 1 and about 10 grams/square meter/day.
25 Those skilled in the art will recognize that water vapor transmission can be thought of as being
inversely proportional to water permeation resistance.

30 Other approaches protect against exposure to undesired elements by applying a blocking
coating to plastic films like PET, to reduce water vapor permeability. These coatings are
typically single layers of inorganic materials like Al, SiO_x, AlO_x and Si₃N₄, deposited onto the
plastic substrates using well-known vacuum deposition processes. A single layer coating of these
inorganic materials typically will reduce the water vapor permeability of PET from 1.0 to 0.1
grams/square meter/day. Thus, single blocking coating on a plastic substrate also fails to meet a
requisite value of permeation resistance.

Figure 1 shows a dyad 10, which refers to a structure that is formed when an inorganic blocking layer or coating 12 is formed atop an organic layer 14 (*e.g.*, acrylic). Dyad 10 may be deposited as a protective layer on a polymeric substrate. Blocking layer 12 consists of densely packed oxide particles and acts as a conventional diffusive barrier, hindering gas and moisture permeation through it. Commonly found defects in a blocking layer, however, allow moisture and ambient gas molecules to diffuse through the oxide particles, and ultimately degrade the underlying electronic devices, such as solar cells and organic light emitting diodes. To overcome the drawbacks associated with the presence of these defects, organic layer 14 is applied to blocking layer 12 as an attempt to smooth defects and the underlying surface of polymeric substrate. Certain other approaches deposit multiple dyads on polymeric substrates serving the predicate that non-aligned defects present in multiple dyads further reduce gas and moisture permeation. However, depositing multiple dyads leads to more expensive barriers as well as reduces the flexibility of the final barrier film.

Regardless of whether a single layer of blocking coating or a single dyad or multiple dyads are used as a protective measure, conventional diffusion retarding schemes described above fail to protect an underlying polymeric layer to the requisite extent for a particular application (*e.g.*, solar cell application and LED display application). Specifically, the defects present in the inorganic layer are not effectively filled-in and provide a diffusion pathway for moisture and undesired ambient gases to travel from the surface of the blocking layer to the polymer substrate. Conventional polymeric substrates are not able to adequately protect the underlying product that it encapsulates from exposure to moisture and undesired ambient gases. As a result, the underlying product degrades over time, eventually failing and suffering from a relatively shorter life span.

What is, therefore, needed are novel protective layer designs that effectively protect underlying moisture and gas sensitive products from moisture and undesired ambient gases, and that do not suffer from the drawbacks encountered by conventional designs of blocking layer and dyads.

SUMMARY OF THE INVENTION

In view of the foregoing, in one aspect, the present invention provides a multilayer stack. The multilayer stack includes: (i) one or more inorganic barrier layers for reducing transport of gas or vapor molecules therethrough; (ii) an inorganic reactive layer disposed adjacent to the one or more inorganic barrier layers, and the reactive layer capable of reacting with the gas or the vapor molecules; and (iii) wherein, in an operational state of the multilayer stack, the vapor or the gas molecules that diffuse through the one or more inorganic barrier layers react with the

inorganic reactive layer, and thereby allow the multilayer stack to be substantially impervious to the gas or the vapor molecules.

The vapor or the gas molecules may include at least one member selected from a group consisting of moisture, oxygen, nitrogen, hydrogen, carbon dioxide, argon and hydrogen sulfide.

5 In accordance with a preferred embodiment of the present invention, the inorganic barrier layer includes at least one member selected from a group consisting of a metal, a metal oxide, a metal nitride, a metal oxy-nitride, a metal carbo-nitride, and a metal oxy-carbide. The metal composition in the inorganic barrier layer preferably includes at least one member selected from a group consisting of aluminum, silver, silicon, zinc, tin, titanium, tantalum, niobium, ruthenium,
10 gallium, platinum, vanadium, indium and carbon.

The inorganic reactive layer preferably includes at least one member selected from a group consisting of alkali metal oxide, zinc oxide, titanium oxide, metal-doped zinc oxide and silicon oxide. In certain embodiments, the inorganic layer of the present invention is doped with one or more non-oxide chemical components.

15 The thickness of each of the inorganic barrier layer and the inorganic reactive layer may be between about 10 nm and about 1 micron. In certain embodiments of the present invention, the one or more barrier layers include two barrier layers, and the reactive layer is sandwiched between the two barrier layers. The reactive layer preferably includes columnar structures. Each of the one or more barrier layers may be made from one or more amorphous materials. The
20 inorganic barrier layers are preferably substantially transparent for applications requiring light transmission.

In another aspect, the present invention provides a solar module. The solar module includes: (i) a solar cell; and (ii) a solar cell encapsulant at least partially encapsulating the solar cell, and the solar cell encapsulant further includes: (a) one or more inorganic barrier layers for
25 reducing transport of gas or vapor molecules therethrough; (b) an inorganic reactive layer disposed adjacent to the one or more inorganic barrier layers, and the reactive layer is capable of reacting with the gas or the vapor molecules; and (c) wherein, in an operational state of the solar cell encapsulant, the vapor or the gas molecules that diffuse through the one or more inorganic barrier layers react with the inorganic reactive layer, and thereby allow the solar cell encapsulant
30 to protect the solar cell from the gas or the vapor molecules. In one embodiment, the solar cell of the present invention is one member selected from a group consisting of a silicon-based solar cell, a thin-film solar cell, an organic photo-voltaic solar cell and a dye-sensitized solar cell. The thin-film solar cell preferably includes at least one member selected from a group consisting of copper, indium, gallium, arsenic, cadmium, tellurium, selenium and sulfur.

In yet another aspect, the present invention provides a light generating module. The light generating module includes: (i) a light source; and (ii) a light source encapsulant at least partially encapsulating the light source, and the light source encapsulant further includes: (a) one or more inorganic barrier layers for reducing transport of gas or vapor molecules therethrough; (b) an inorganic reactive layer disposed adjacent to the one or more inorganic barrier layers, and the reactive layer capable of reacting with the gas or the vapor molecules; and (c) wherein, in an operational state of the light source encapsulant, the vapor or the gas molecules that diffuse through the one or more inorganic barrier layers react with the inorganic reactive layer, and thereby allow the light source encapsulant to protect the light source from the gas or the vapor molecules. In certain embodiments, the light source of the present invention includes organic or inorganic light emitting diodes.

In yet another aspect, the present invention includes a light emitting diode ("LED") display. The LED display includes: (i) an LED; and (ii) an LED encapsulant at least partially encapsulating the LED, and the LED encapsulant further includes: (a) one or more inorganic barrier layers for reducing transport of the gas or the vapor molecules therethrough; (b) an inorganic reactive layer disposed adjacent to the one or more inorganic barrier layers, and the reactive layer is reactive with the gas or the vapor molecules; and (c) wherein, in an operational state of the LED encapsulant, the vapor or the gas molecules that diffuse through the one or more inorganic barrier layers react with the inorganic reactive layer, and thereby allow the LED encapsulant to protect the LED from the gas or the vapor molecules. In certain embodiments, the LED of the present invention includes organic light emitting diodes, also known as OLED's.

In yet another aspect, the present invention provides an electrolytic cell. The electrolytic cell includes: (i) a cathode; (ii) an anode; (iii) an electrolyte; and (iv) an electrolytic cell encapsulant at least partially encapsulating the cathode, the anode and the electrolyte, the electrolytic cell encapsulant further includes: (a) one or more inorganic barrier layers for reducing transport of the gas or the vapor molecules therethrough; (b) an inorganic reactive layer disposed adjacent to the one or more inorganic barrier layers, and the reactive layer is reactive with the gas or the vapor molecules; and (c) wherein, in an operational state of the electrolytic cell encapsulant, the vapor or the gas molecules that diffuse through the one or more inorganic barrier layers react with the inorganic reactive layer, and thereby allow the electrolytic cell encapsulant to protect the electrolytic cell from the gas or the vapor molecules. In certain embodiments, the electrolytic cell of the present invention is flexible.

In another aspect, the present invention provides a reflective display module. The reflective display module includes: (i) a reflective display; and (ii) a reflective display encapsulant at least partially encapsulating the reflective display, and the reflective display

encapsulant including: (a) one or more inorganic barrier layers for reducing transport of gas or vapor molecules therethrough; (b) an inorganic reactive layer disposed adjacent to the one or more inorganic barrier layers, and the reactive layer capable of reacting with the gas or the vapor molecules; and (c) wherein, in an operational state of the reflective display encapsulant, the
5 vapor or the gas molecules that diffuse through the one or more inorganic barrier layers react with the inorganic reactive layer, and thereby allow the reflective display encapsulant to protect the reflective display from the gas or the vapor molecules. The reflective display includes an electrophoretic display or a multi-layer liquid crystal display.

In yet another aspect, the present invention provides a process of fabricating a multilayer
10 stack. The process includes: (i) loading a flexible substrate on a coating machine; (ii) displacing the flexible substrate or a portion of the coating machine such that the flexible substrate acquires a first position inside the coating machine; (iii) fabricating one or more inorganic barrier layers on the flexible substrate when the flexible substrate is at the first position, and the inorganic
15 barrier layer capable of reducing transport of vapor or gas molecules therethrough; (iv) displacing the flexible substrate or the coating machine such that the flexible substrate acquires a second position inside the coating machine, and the second position is different from the first position; and (v) forming a reactive layer adjacent to the one or more barrier layers, the reactive layer being reactive to the vapor or the gas molecules that diffuse through the inorganic barrier layer, and the one or more barrier layers and the reactive layer on the flexible substrate combine
20 to form the multilayer stack.

The above-described process preferably includes applying the multilayer stack to at least one member selected from a group consisting of a solar cell, a light source and a light emitting diode display, and an electrolytic cell. The fabricating step may include at least one technique selected from a group consisting of sputtering, reactive sputtering, evaporation, reactive
25 evaporation, chemical vapor deposition, solution coating process and plasma enhanced chemical vapor deposition. Similarly, forming the reactive layer preferably includes at least one technique selected from a group consisting of sputtering, reactive sputtering, evaporation, reactive evaporation, chemical vapor deposition, solution coating process and plasma enhanced chemical vapor deposition. The fabricating step may be carried out at a temperature that is between about -
30 20°C and about 200 °C and forming the reactive layer is preferably carried out at a temperature that is between about -20°C and about 200 °C. Each of the fabricating step and the forming step are carried out in a roll-to-roll operation.

The loading step in the above-described process preferably includes: (a) positioning
35 inside the coating machine the flexible substrate wrapped around a spool; and (b) extending and securing the flexible substrate to a take-up spool such that at least a portion of the flexible

substrate is exposed to allow for the fabricating step. During the fabricating and the forming steps in the above-described process, the substrate may contact a drum, which is set at a temperature that is between about -20 °C and about 200 °C.

In yet another aspect, the present invention provides a composition of a multilayer barrier stack. The composition includes: (i) an inorganic barrier layer for reducing transport of gas or vapor molecules therethrough, and the inorganic barrier layer including at least one member selected from a group consisting of a metal, a metal oxide, a metal nitride, a metal oxy-nitride, a metal carbo-nitride, and a metal oxy-carbide -nitride; and (ii) an inorganic reactive layer including an effective amount of a reactive material to react with the gases or the vapor molecules that have diffused through the organic barrier layer, and the reactive material includes at least one material selected from a group consisting of alkali metal oxide, zinc oxide, titanium oxide, metal-doped zinc oxide and silicon oxide. At least one member in said inorganic barrier layer may have a concentration that is a value between about 1% (by weight) and about 100% (by weight) and, similarly, at least one reactive material may have a concentration that is a value between about 1% (by weight) and about 100% (by weight).

The construction and method of operation of the invention, however, together with additional objects and advantages thereof, will be best understood from the following descriptions of specific embodiments when read in connection with the accompanying figures.

BRIEF DESCRIPTION OF THE DRAWINGS

Figure 1 shows a cross-sectional view of a conventional blocking coating used for encapsulating solar cells.

Figure 2 shows a multilayer barrier stack, according to one embodiment of the present invention, for protecting against moisture and other undesirable ambient gases.

Figure 3 shows a side-sectional view of a multilayer barrier stack, according to another embodiment of the present invention, for protecting against moisture and other undesirable ambient gases.

Figure 4 is a perspective view of a columnar reactive layer structure, according to one embodiment of the present invention that may be used in the multilayer barrier stack of Figures 2 and/or 3.

Figure 5 is a top view of a coating machine, according to one embodiment of the present invention that facilitates roll-to-roll manufacture of the inventive multilayer stacks.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

In the following description, numerous specific details are set forth in order to provide a thorough understanding of the present invention. It will be apparent, however, to one skilled in the art that the present invention may be practiced without limitation to some or all of these
5 specific details. In other instances, well-known process steps have not been described in detail in order to not unnecessarily obscure the invention.

Figure 2 shows a multilayer stack 200, in which a barrier layer 202 is disposed adjacent to a reactive layer 204. Multilayer stack 200 is fabricated on a substrate, preferably a flexible one made from plastic. In accordance with a preferred embodiment, multilayer stack of the present
10 invention serves as an encapsulant for a variety of applications. By way of example, a plastic substrate with multilayer stack 200 fabricated thereon is used for encapsulating solar cells, electrolytic cells, light generating modules, light emitting diode ("LED") displays and reflective displays to protect the underlying structure from exposure to moisture and undesirable or ambient gases.

15 In multilayer stack 200, barrier layer 202 serves as a barrier to moisture and undesired gases, such as oxygen, nitrogen, hydrogen, carbon dioxide, argon and hydrogen sulfide. Barrier layer 202 includes at least one material selected from a group consisting of a metal, metal oxide, a metal nitride, a metal oxy-nitride, a metal carbo-nitride and a metal oxy-carbide. Furthermore, barrier layer 102 preferably includes carbon or oxygen, in their elemental form or as part of
20 chemical compounds. Examples of barrier layer 202 include silicon oxide, aluminum oxide, aluminum nitride, aluminum oxy-nitride, tantalum oxide, niobium oxide, silicon nitride, silicon oxy-nitride, silicon oxy-carbide and silicon carbo-nitride.

Barrier layer 202 may be made from one or more layers of an inorganic material. In preferred embodiments of the present invention, barrier layer 202 includes an amorphous
25 material. When more than one inorganic layer is used, the different layers are preferably stacked adjacent each other. It is not necessary that the type of inorganic material used in each layer is the same, and may be different in certain embodiments of the present invention. Although barrier layer 202 may be made from any inorganic material that serves as a barrier to the above-mentioned ambient gases, in preferred embodiments of the present invention, barrier layer 202
30 includes a metal composition, present in its elemental form or as a compound (as described above), that includes at least one member selected from a group consisting of aluminum, silver, silicon, zinc, tin, titanium, tantalum, niobium, ruthenium, gallium, platinum, vanadium, and indium. By way of example, a metal oxide includes Al_xO_y or SiO_x . In barrier layer 202, the presence of effective amount of metals or metal oxides reduces transport of undesired gas or

vapor molecules through the barrier layer. In preferred embodiments of the present invention, in barrier layer 202, metals or metal oxides have a concentration that is between about 1% (by weight) and about 100% (by weight), and preferably between about 1% (by weight) and about 50% (by weight).

5 Barrier layer 202 has a thickness that is between about 10 nm and about 1 micron, and preferably between about 20 nm and about 300 nm.

Barrier layer 202 is designed to reduce transport of gas or vapor molecules therethrough, but is not completely impervious to moisture and certain molecules of undesired gases. To this end, the present invention employs a reactive layer 204, which is designed to react with moisture and molecules of undesired gases, *e.g.*, oxygen, nitrogen, hydrogen, carbon dioxide, argon and hydrogen sulfide, that diffuse through barrier layer 202. According to conventional wisdom, the reactive nature of reactive layer 204 is undesirable in solar cell and other applications, because it absorbs moisture and undesirable ambient gases, causing product performance degradation and eventually leading to product failure. The present invention, however, innovatively uses the reactive nature of reactive layer 204 in a manner that is useful for barrier stack applications. Specifically, moisture and ambient or undesired gases that diffuse through barrier layer 202 react with reactive layer 204, allowing multilayer stack 200 to be substantially impervious to the diffused gas or vapor molecules.

Reactive layer 204 may be made from any inorganic material and is preferably chemically homogenous. In preferred embodiments of the present invention, however, reactive layer 204 include at least one reactive material selected from a group consisting of alkali metal oxide, zinc oxide, titanium oxide, metal-doped zinc oxide and silicon oxide. In certain embodiments of the present invention, reactive layer 204 is doped with one or more non-oxide chemical components. Representative examples of such non-oxide dopant materials include alkali metals, such as calcium, sodium and lithium.

Each of one or more reactive layers may be made from the same material or from different materials. Like barrier layer 202, reactive layer 204 may include one or more reactive layers that are disposed adjacent to each other. Reactive layer 204 includes an effective amount of a reactive material to react with the moisture and undesired or ambient gases that have diffused through an adjacent barrier layer. In preferred embodiments of the present invention, in reactive layer 204, reactive material has a concentration that is between about 1% (by weight) and about 100% (by weight). In more preferred embodiments of the present invention, however, reactive material in reactive layer 204 has a concentration that is between about 90% (by weight) and about 100% (by weight).

Reactive layer 204 may have a total thickness that is between about 10 nm and about 1 micron and that is preferably between about 20 nm and about 500 nm. In certain applications where multilayer stack 200 is fabricated on a plastic substrate and used as an encapsulant, there is a risk that during shipping, handling and storage of the encapsulated product, moisture and undesired ambient gases diffuse through the plastic substrate and react with reactive layer 204. As a result, the required reactive property of reactive layer 204 is depleted, rendering the multilayer stack 200 ineffective. To this end, certain preferred embodiments of the present invention provide an extra barrier layer which is disposed between the plastic substrate and the reactive layer.

If reactive layer 204 is compositionally similar to barrier layer 202, then it is preferable to have the reactive layer sufficiently different from the barrier layer in structure, degree of doping, degree of crystallinity (including a scenario where one layer is amorphous, while the other is not), or reactivity to bind with moisture or undesired ambient gases.

Figure 3 shows a multi-layer stack 300, according to alternate embodiment of the present invention. Multi-layer stack 300 includes a reactive layer 304 that is sandwiched between two barrier layers 302 and 306. Reactive layer 304 of Figure 3 is substantially similar to reactive layer 204 of Figure 2, and barrier layers 302 and 306 of Figure 3 are substantially similar to barrier layer 202 of Figure 2. Like multilayer stack 200, multilayer stack 300 is also fabricated on any substrate. In preferred embodiments of the present invention, however, stack 300 is fabricated on a flexible, plastic substrate.

In the configuration of the multilayer stack shown in Figure 3, moisture or molecules of undesired or ambient gas that diffuse through the plastic substrate are blocked by barrier layer 302 before they reach reactive layer 304. Barrier layer 302 consequently protects reactive layer 304 against moisture and undesired or ambient gases that diffuses through the polymeric substrate backing.

Regardless of whether multilayer stack 200 of Figure 2 or multilayer stack 300 of Figure 3 is used, a component reactive layer preferably has a columnar structure 404, shown in Figure 4, disposed as a reactive layer (*e.g.*, reactive layer 204 of Figure 2 or reactive layer 304 of Figure 3). A reactive layer having a columnar structure represents a preferred embodiment of the present invention because such structure provides more active surface area that reacts with the diffused chemical species.

Although inventive barrier and reactive layers of Figures 2 and 3 are shown to contact each other, it is not necessary that they do so. In certain embodiments of the present invention, an intermediate layer, serving one or more of variety of functions, may be interposed between the barrier and the reactive layers. By way of example, an intermediate layer may be used to

planarize either or both of the surfaces of the barrier and the reactive layers, between which it is interposed. As a result, in those instances where the specification describes that a barrier layer is disposed adjacent to a reactive layer, the term “adjacent” is not limited to embodiments where the barrier and the reactive layers contact each other and also covers those embodiments where one or more intermediate layers are interposed between the barrier and the reactive layers.

Furthermore, according to the above-described preferred embodiments, each of inventive barrier and reactive layers are made from one or more different types of inorganic materials. However, in other embodiments of the present invention, the inventive barrier and reactive layers are not so limited. In certain embodiments of the present invention, each of barrier and reactive layers are made from one or more different types of organic materials.

In preferred embodiments of the present invention, multilayer stack 200 of Figure 2 and multilayer stack 300 of Figure 3 are used as an encapsulant. By way of example, in a solar cell application, the inventive multilayer stacks are used to encapsulate a solar cell. As another example, in a lighting application, where a light generating module is used, the inventive multilayer stacks are used to encapsulate a light source. As yet another example, in an electrolytic cell application, the inventive multilayer stacks is used to encapsulate a cathode, an anode and an electrolyte. As yet another example, in display applications, the inventive multilayer stacks are used to encapsulate displays, such as an LED display or a reflective display. Those skilled in the art will recognize that encapsulation of solar cells, light generating modules, electrolytic cells, LED displays and reflective displays is carried out using techniques well known to those skilled in the art.

According to conventional wisdom, when one layer is fabricated adjacent to another layer to form a multilayer stack, a defect present in one layer undesirably propagates to the adjacent layer. The defect propagation problem exacerbates as the number of layers in the multilayer stack increases. In sharp contrast, the present invention has surprisingly and unexpectedly found that an inorganic layer covers defects found in and smoothens the adjacent layer. As a result, inventive multilayer stacks are particularly advantageous for moisture and vapor barrier applications because they prevent or significantly reduce the propagation of defects or undesired structure from one layer to another.

Although inventive multilayer stacks can be made using any technique well known to those skilled in the art, using a roll-to-roll technique, which provides a relatively high throughput, represents a preferred embodiment of the present invention. Figure 5 shows a top view of a coating machine 500, according to one embodiment of the present invention. The coating machine is also called a “roll coater” as it coats a roll of flexible film. Coating machine 500 includes an unwind roller 502, an idle roller 504, a takeup roller 506, a temperature

controlled deposition drum 508, one or more deposition zones 510, and a deposition chamber 512. Each of one or more deposition zones 510 includes a target material that is ultimately deposited on flexible substrate, a power supply and shutters, as explained below.

A coating process, according to one embodiment of the present invention, begins when a flexible substrate 514 is loaded onto unwind roller 502. Flexible substrate 514 is preferably wrapped around a spool that is loaded onto unwind roller 502. Typically a portion of the wrapped flexible substrate is pulled from the spool and guided around idle rollers 504 and deposition drum 508, which is capable of rotating, so that it connects to takeup roller 506. In the operating state of coating machine 500, unwind roller 502, takeup roller 506 and deposition drum 508 rotate, causing flexible substrate 514 to displace along various locations around cooled deposition drum 508.

Once flexible substrate 514 is loaded inside coating machine 500, the coating process includes striking a plasma inside deposition zone 510. Shutters in the coating zones direct charged particles in the plasma field to collide with and eject the target material so that it is deposited on the flexible substrate. During the coating process, a temperature of flexible substrate 514 is controlled using deposition drum 508 preferably to values such that no damage is done to the substrate. In those embodiments of the present invention where flexible substrate 514 includes a polymeric material, deposition drum 508 is cooled such that the temperature of the deposition drum is preferably near or below a glass transition temperature of the polymeric material. Such cooling action prevents melting of the polymer-based substrate during the deposition process, and thereby avoids degradation of the polymer-based substrate that might occur in the absence of deposition drum 508.

As can be seen from Figure 5, multiple deposition zones are provided, each of which may be dedicated to effecting deposition of one particular material on the polymeric substrate. By way of example, the target material, in one of the deposition zones, includes at least one member selected from a group consisting of a metal, a metal oxide, a metal nitride, a metal oxy-nitride, a metal carbo-nitride, and a metal oxy-carbide to facilitate deposition of a barrier layer (*e.g.*, to fabricate barrier layer 202 of Figure 2 or fabricate at least one of barrier layers 302 and 306 of Figure 3). As another example, the target material in another of the deposition zones includes at least one member selected from a group consisting of alkali metal oxide, zinc oxide, titanium oxide, metal-doped zinc oxide and silicon oxide to fabricate a reactive layer (*e.g.*, to fabricate reactive layer 204 of Figure 2 or reactive layer 304 of Figure 3). By displacing flexible substrate 514 from one location to another, different types and different thicknesses of target material, at different deposition zones, can be deposited on the substrate. Coating machine 500 can be used to implement at least one technique selected from a group consisting of sputtering, reactive ion

sputtering, evaporation, reactive evaporation, chemical vapor deposition and plasma enhanced chemical vapor deposition.

It is noteworthy that instead of displacing the substrate from one position to another to facilitate deposition of multiple layers, the inventive features of the present invention can be realized by holding the substrate stationary and displacing at least a portion of the coating machine or by displacing both the substrate and the coating machine.

Regardless of the specific process implemented for deposition, it will be appreciated that the roll-to-roll technique of the present invention allows for very rapid deposition of different types and thicknesses of layers on a substrate to form the inventive multilayer stacks. The inventive roll-to-roll fabrication process realizes a very high throughput, which translates into increased revenue. Against the current backdrop where the solar cell industry is being challenged to become a commercially viable alternate energy solution, the inventive multilayer stacks and processes represent a marked improvement over the conventional designs and processes.

As explained above, barrier and reactive layers in multilayer stack 300 of Figure 3 may be made from appropriate inorganic oxide materials such that the resulting multilayer stacks are both flexible and impervious to water vapor. The present invention recognizes that if the amount of water vapor adsorption through the barrier layer is limited, then the reactive layer inside the multilayer stack enjoys an extended life span. Moreover, the present invention also recognizes that limited adsorption is achieved by minimizing the amount of water vapor arriving at the interface of the barrier and the reactive layers.

Although illustrative embodiments of this invention have been shown and described, other modifications, changes, and substitutions are intended. By way of example, the present invention discloses barriers of simple gases and water vapor; however, it is also possible to reduce the transport of organic material using the systems, processes, and compositions of the present invention. Accordingly, it is appropriate that the appended claims be construed broadly and in a manner consistent with the scope of the disclosure, as set forth in the following claims.

CLAIMS

What is claimed is:

1. A multilayer stack, comprising:
one or more inorganic barrier layers for reducing transport of gas or vapor molecules
5 therethrough;
an inorganic reactive layer disposed adjacent to said one or more inorganic barrier layers,
and said reactive layer capable of reacting with said gas or said vapor molecules; and
wherein, in an operational state of said multilayer stack, said vapor or said gas molecules
that diffuse through said one or more inorganic barrier layers react with said inorganic reactive
10 layer, and thereby allow said multilayer stack to be substantially impervious to said gas or said
vapor molecules.
2. The multilayer stack of claim 1, wherein said vapor or said gas molecules includes at
least one member selected from a group consisting of moisture, oxygen, nitrogen, hydrogen,
carbon dioxide, argon and hydrogen sulfide.
- 15 3. The multilayer stack of claim 1, wherein said inorganic barrier layer includes at least one
member selected from a group consisting of a metal, a metal oxide, a metal nitride, a metal oxy-
nitride, a metal carbo-nitride, and a metal oxy-carbide.
4. The multilayer stack of claim 3, wherein said inorganic barrier layer includes at least one
member selected from a group consisting of aluminum, silver, silicon, zinc, tin, titanium,
20 tantalum, niobium, ruthenium, gallium, platinum, vanadium and indium.
5. The multilayer stack of claim 1, wherein said inorganic reactive layer includes at least
one member selected from a group consisting of alkali metal oxide, zinc oxide, titanium oxide,
metal-doped zinc oxide and silicon oxide.
6. The multilayer stack of claim 5, wherein said inorganic reactive layer is doped with one
25 or more non-oxide chemical components.
7. The multilayer stack of claim 5, wherein said inorganic reactive layer includes an
inorganic matrix.
8. The multilayer stack of claim 1, wherein the thickness of said inorganic barrier layer is
between about 10 nm and about 1 micron.
- 30 9. The multilayer stack of claim 1, wherein the thickness of said inorganic reactive layer is
between about 10 nm and about 1 micron.
10. The multilayer stack of claim 1, wherein said one or more barrier layers includes two
barrier layers, and said reactive layer is sandwiched between said two barrier layers.
11. The multilayer stack of claim 1, wherein said reactive layer includes columnar structures.

12. The multilayer stack of claim 1, wherein each of said one or more barrier layers are made from one or more amorphous materials.

13. The multilayer stack of claim 1, wherein said inorganic barrier layer is substantially transparent.

5 14. A solar module comprising:

a solar cell; and

a solar cell encapsulant at least partially encapsulating said solar cell, and said solar cell encapsulant including:

one or more inorganic barrier layers for reducing transport of gas or vapor

10 molecules therethrough;

an inorganic reactive layer disposed adjacent to said one or more inorganic barrier layers, and said reactive layer capable of reacting with said gas or said vapor molecules; and

wherein, in an operational state of said solar cell encapsulant, said vapor or said

gas molecules that diffuse through said one or more inorganic barrier layers react with said

15 inorganic reactive layer, and thereby allow said solar cell encapsulant to protect said solar cell from said gas or said vapor molecules.

15. The solar module of claim 13, wherein said solar cell is one member selected from a group consisting of a silicon-based solar cell, a thin-film solar cell, a organic photo-voltaic solar cell and a dye-sensitized solar cell.

20 16. The solar module of claim 13, wherein said thin-film solar cell includes at least one member selected from a group consisting of copper, indium, gallium, arsenic, cadmium, tellurium, selenium and sulfur.

17. A light generating module, comprising:

a light source; and

25 a light source encapsulant at least partially encapsulating said light source, and said light source encapsulant including:

one or more inorganic barrier layers for reducing transport of gas or vapor molecules therethrough;

30 an inorganic reactive layer disposed adjacent to said one or more inorganic barrier layers, and said reactive layer capable of reacting with said gas or said vapor molecules; and

wherein, in an operational state of said light source encapsulant, said vapor or said gas molecules that diffuse through said one or more inorganic barrier layers react with said inorganic reactive layer, and thereby allow said light source encapsulant to protect said light source from said gas or said vapor molecules.

18. The light generating module of claim 16, wherein said light source includes organic or inorganic light emitting diodes.

19. A light emitting diode display, comprising:

a light emitting diode; and

5 a light emitting diode encapsulant at least partially encapsulating said light emitting diode, said light emitting diode encapsulant including:

one or more inorganic barrier layers for reducing transport of said gas or said vapor molecules therethrough;

10 an inorganic reactive layer disposed adjacent to said one or more inorganic barrier layers, and said reactive layer is reactive with said gas or said vapor molecules; and

wherein, in an operational state of said light emitting diode encapsulant, said vapor or said gas molecules that diffuse through said one or more inorganic barrier layers react with said inorganic reactive layer, and thereby allow said light emitting diode encapsulant to protect said light emitting diode from said gas or said vapor molecules.

15 20. The light emitting diode display of claim 18, wherein said light emitting diode includes organic light emitting diodes, also known as OLED's.

21. An electrolytic cell, comprising:

a cathode;

an anode;

20 an electrolyte; and

an electrolytic cell encapsulant at least partially encapsulating said cathode, said anode and said electrolyte, said electrolytic cell encapsulant including:

one or more inorganic barrier layers for reducing transport of said gas or said vapor molecules therethrough;

25 an inorganic reactive layer disposed adjacent to said one or more inorganic barrier layers, and said reactive layer is reactive with said gas or said vapor molecules; and

wherein, in an operational state of said electrolytic cell encapsulant, said vapor or said gas molecules that diffuse through said one or more inorganic barrier layers react with said inorganic reactive layer, and thereby allow said electrolytic cell encapsulant to protect said
30 electrolytic cell from said gas or said vapor molecules.

22. The electrolytic cell of claim 20, wherein said electrolytic cell is flexible and lightweight.

23. A reflective display module, comprising:

a reflective display; and

35 a reflective display encapsulant at least partially encapsulating said reflective display, and said reflective display encapsulant including:

one or more inorganic barrier layers for reducing transport of gas or vapor molecules therethrough;

an inorganic reactive layer disposed adjacent to said one or more inorganic barrier layers, and said reactive layer capable of reacting with said gas or said vapor molecules; and

5 wherein, in an operational state of said reflective display encapsulant, said vapor or said gas molecules that diffuse through said one or more inorganic barrier layers react with said inorganic reactive layer, and thereby allow said reflective display encapsulant to protect said reflective display from said gas or said vapor molecules.

24. The reflective display module of claim 23, wherein said reflective display includes an
10 electrophoretic display or a multi-layer liquid crystal display.

25. A process of fabricating multilayer stack, said process comprising:

loading a flexible substrate on a coating machine;

displacing said flexible substrate or a portion of said coating machine such that said flexible substrate acquires a first position inside said coating machine;

15 fabricating one or more inorganic barrier layers on said flexible substrate when said flexible substrate is at said first position, and said inorganic barrier layer capable of reducing transport of vapor or gas molecules therethrough;

displacing said flexible substrate or said coating machine such that said flexible substrate acquires a second position inside said coating machine, and said second position is different from
20 said first position; and

forming a reactive layer adjacent to said one or more barrier layers, said reactive layer is reactive to said vapor or said gas molecules that diffuse through said inorganic barrier layer, and said one or more barrier layers and said reactive layer on said flexible substrate combine to form a multilayer stack.

25 26. The process of claim 25, further comprising applying said multilayer stack to at least one member selected from a group consisting of a solar cell, a light source and a light emitting diode display, and an electrolytic cell.

27. The process of claim 25, wherein said fabricating includes at least one technique selected from a group consisting of sputtering, reactive sputtering, evaporation, reactive evaporation,
30 chemical vapor deposition, solution coating process and plasma enhanced chemical vapor deposition.

28. The process of claim 25, wherein said forming said reactive layer includes at least one technique selected from a group consisting of sputtering, reactive sputtering, evaporation, reactive evaporation, chemical vapor deposition, solution coating process and plasma enhanced
35 chemical vapor deposition.

29. The process of claim 25, wherein said fabricating is carried out at a temperature that is between about -20°C and about 200 °C.
30. The process of claim 25, wherein said forming said reactive layer is carried out at a temperature that is between about -20°C and about 200 °C.
- 5 31. The process of claim 25, wherein each of said fabricating said one or more barrier layers and said forming said reactive layer are carried out in a roll-to-roll operation.
32. The process of claim 25, wherein said loading includes:
positioning inside said coating machine said flexible substrate wrapped around a spool;
and
10 extending and securing said flexible substrate to a take-up spool such that at least a portion of said flexible substrate is exposed to allow for said fabricating.
33. The process of claim 25, wherein during said fabricating and said forming said substrate contacts a drum, which is set at a temperature that is between about -20 °C and about 200 °C.
34. A composition of a multilayer barrier stack, comprising:
15 an inorganic barrier layer for reducing transport of gas or vapor molecules therethrough, and said inorganic barrier layer including at least one member selected from a group consisting of a metal, a metal oxide, a metal nitride, a metal oxy-nitride, a metal carbo-nitride, and a metal oxy-carbide -nitride; and
an inorganic reactive layer including an effective amount of a reactive material to react
20 with said gases or said vapor molecules that have diffused through said organic barrier layer, and said reactive material includes at least one material selected from a group consisting of alkali metal oxide, zinc oxide, titanium oxide, metal-doped zinc oxide and silicon oxide.
35. The composition of claim 34, wherein said at least one member in said inorganic barrier layer has a concentration that is between about 1% (by weight) and about 100% (by weight).
- 25 36. The composition of claim 34, wherein said at least one reactive material has a concentration that is between about 1% (by weight) and about 100% (by weight).

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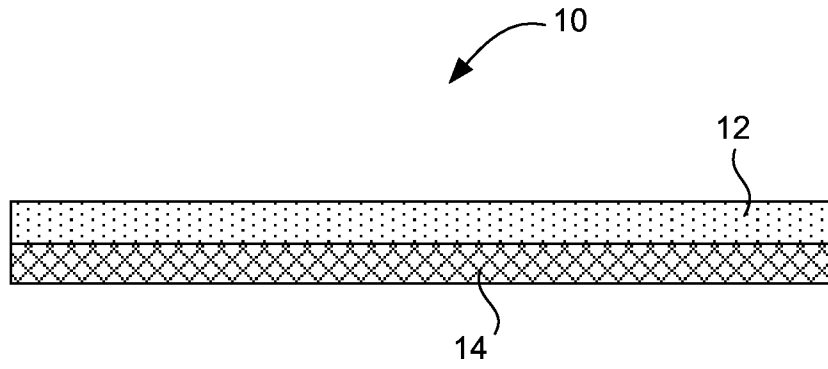


Figure 1

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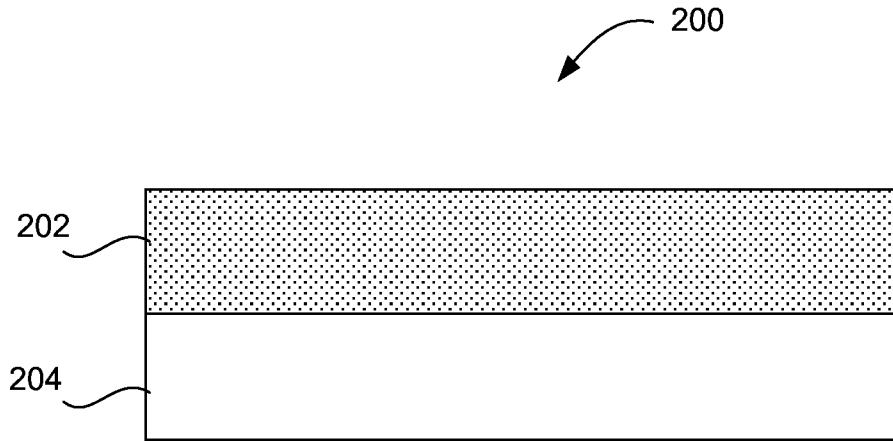


Figure 2

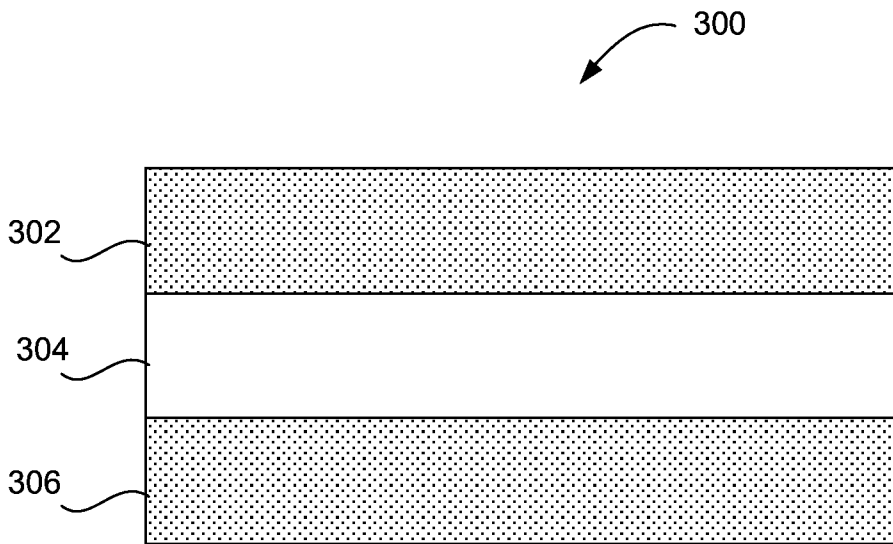


Figure 3

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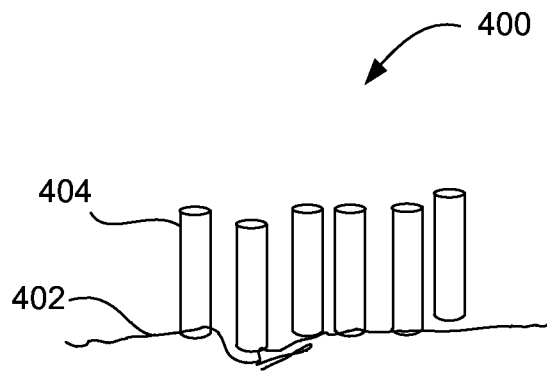


Figure 4

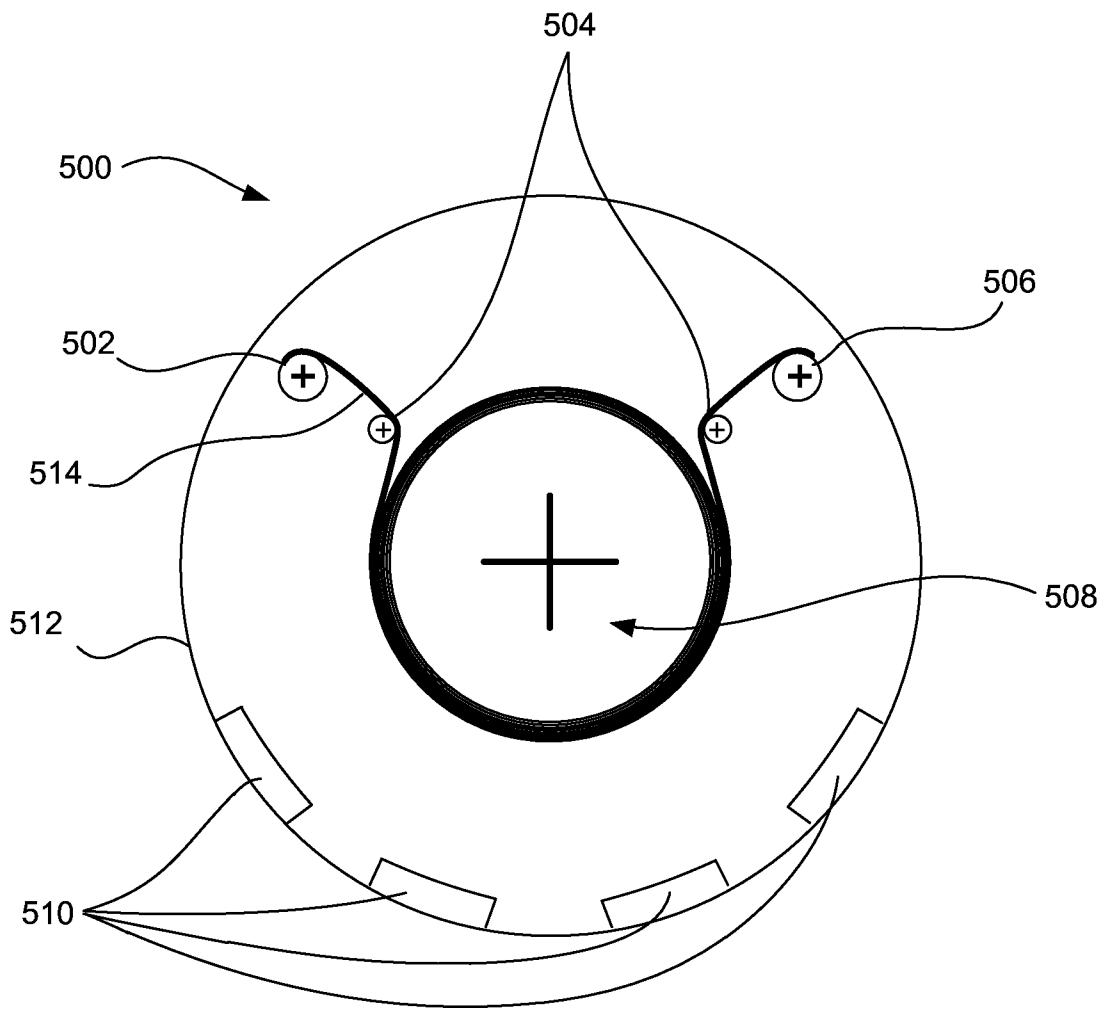


Figure 5